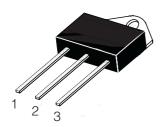
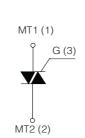


INSULATED TO3P





Gate Trigger Current On-State Current 25 Amp Off-State Voltage

≤ 100 mA

600 V ÷ 800 V

FEATURES

- Provides voltage insulated tab (rated at 2500V RMS)
- Glass/passivated die junctions
- High current Triac
- Low thermal resistance
- High surge current capability
- Low forward voltage drop
- Solder dip 260°C, 10s
- Component in accordance to RoHS 2011/65/EU and WEEE 2002/96/EC



- Meets MSL level 3, per J-STD-020, LF maximum peak of 260° C
- Certified compliance of UL 1557 Standard for Electrically Isolated Semiconductors. Fille reference E320541, Vol. 3

MECHANICAL DATA

- Case: INSULATED TO3P. Epoxy meets UL 94V-0 flammability rating.
- Polarity: As marked on the body.
- **Terminals:** Matte tin plated leads, solderable per MIL-STD-750 Method 2026, J-STD-002 and JESD22-B102. Consumer grade, meets JESD 201 class 1A whisker test.

TYPICAL APPLICATIONS

Suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers.

Maximun Ratings and Electrical Characteristics at 25°C

SYMBOL	PARAMETER	CONDITIONS	Value	Unit
I _{T(RMS)}	RMS On-state Current (full sine wave)	All Conduction Angle, T _c = 100 °C	25	А
I _{TSM}	Non-repetitive On-State Current	Full Cycle, 60 Hz (t = 16.7 ms)	260	А
I _{TSM}	Non-repetitive On-State Current	Full Cycle, 50 Hz (t = 20 ms)	250	А
I ² t	Fusing Current	tp = 10 ms, Half Cycle	340	A ² s
I _{GM}	Peak Gate Current	20 μs max. Tj = 125 °C	4	А
P _{G(AV)}	Average Gate Power Dissipation	Tj = 125 °C	1	W
dl/dt	Critical rate of rise of on-state current	$I_G = 2x I_{GT}, t_r \le 100 \text{ns}$ $f = 120 \text{ Hz}, T_i = 125 ^{\circ}\text{C}$	50	A/µs
T _j	Operating Temperature	, ,	(-40 +150)	°C
T _{stg}	Storage Temperature		(-40 +125)	°C
T _{sld}	Soldering Temperature	10s max	260	°C
V _{iso}	R.M.S. isolation voltage 50/60 Hz sinusoidal waveform		2.500	Vac

	SYMBOL	PARAMETER	VOLT	Unit	
OTWIBOL	T / W / WILL LIN	М	N		
	V_{DRM}/V_{RRM}	Repetitive Peak Off State Voltage	600	800	V

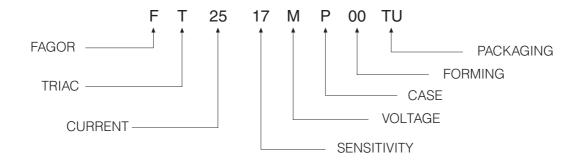


Electrical Characteristics at Tamb = 25 °C

SYMBOL	PARAMETER	CONDITIONS	Quadrant		SENSITIVITY 17	Unit
IGT (1)	Gate Trigger Current	$V_D = 12 V_{DC}, R_L = 33\Omega, T_j = 25 ^{\circ}C$	Q1÷Q3	MAX	50	mA
			Q4	MAX	100	mA
V _{GT}	Gate Trigger Voltage	$V_D = 12 V_{DC}, R_L = 33\Omega, T_j = 25 ^{\circ}C$	Q1÷Q4	MAX	1.3	V
V_{GD}	Gate Non Trigger Voltage	$V_D = V_{DRM}, R_L = 3.3 \text{ K}\Omega, T_j = 125 \text{ °C}$	Q1÷Q4	MIN	0.2	V
I _H ⁽²⁾	Holding Current	I_T = 100 mA, Gate open, T_j = 25 °C		MAX	80	mA
IL	Latching Current	$I_{G} = 1.2 I_{GT}, T_{j} = 25 ^{\circ}\text{C}$	Q1,Q3,Q4	MAX	70	mA
			Q2	MAX	160	mA
dV/dt (2)	Critical Rate of Voltage Rise	$V_D = 0.67 \text{ x VDRM}$, Gate open $T_j = 125 ^{\circ}\text{C}$		MIN	500	V/µs
(dV/dt)c (2)	Critical rise rate of Commutating off-state voltage	$(dI/dt)c = 2.7 \text{ A/ms}$ $T_j = 125 ^{\circ}\text{C}$		MIN	10	V/µs
V _{TM} ⁽²⁾	On-state Voltage	$I_T = 35 \text{ Amp, tp} = 380 \mu\text{s,} T_j = 25 ^{\circ}\text{C}$		MAX	1.55	V
V _{t (o)} (2)	Threshold Voltage	T _j = 125 °C		MAX	0.85	V
r _d ⁽²⁾	Dynamic resistance	T _j = 125 °C		MAX	16	mΩ
I _{DRM} /I _{RRM}	Off-State Leakage Current	$V_D = V_{DRM}$, $T_j = 125 ^{\circ}C$		MAX	3	mA
		$V_R = V_{RRM}$, $T_j = 25 ^{\circ}C$		MAX	5	μΑ
R _{th(j-c)}	Thermal Resistance Junction-Case	for AC 360° conduction angle			0.9	°C/W
R _{th(j-a)}	Thermal Resistance Junction-Ambient				60	°C/W

⁽¹⁾ Minimum I_{GT} is guaranted at 5% of I_{GT} max.

Part Number Information



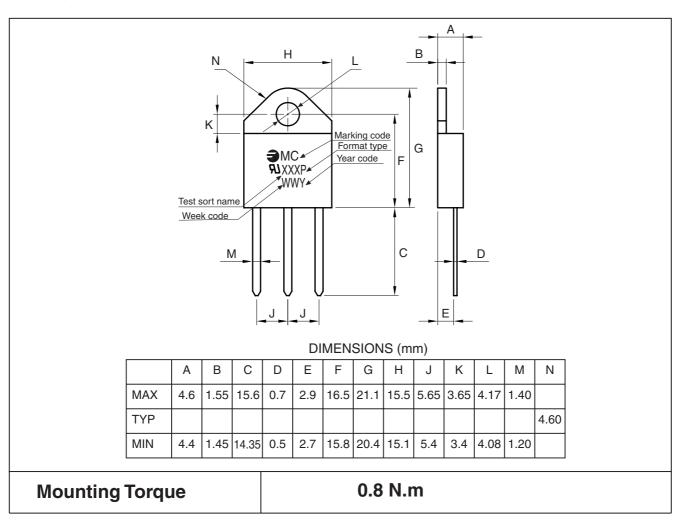
⁽²⁾ For either polarity of electrode MT2 voltage with reference to electrode MT1.



Ordering information

PREFERRED P/N	PACKAGE CODE	DELIVERY MODE	BASE QUANTITY	UNIT WEIGHT (g)
FT2517MP 00TUC	TU	TUBE	450	4.50

Package Outline Dimensions: (mm) INSULATED TO3P





Ratings and Characteristics (Ta 25 °C unless otherwise noted)

FIG.1:Maximum power dissipation versus RMS on-state current(full cycle)

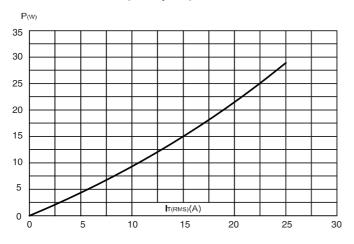


FIG.3:On-state characteristics (maximum values).

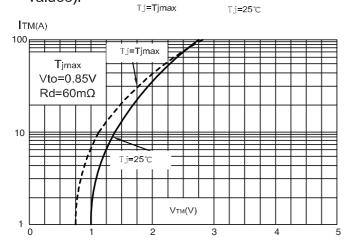


FIG.5:Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms,and corresponding value of l²t.

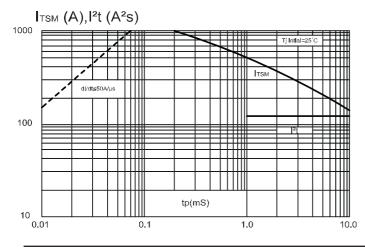


FIG.2:RMS on-state current versus case temperature(full cycle)

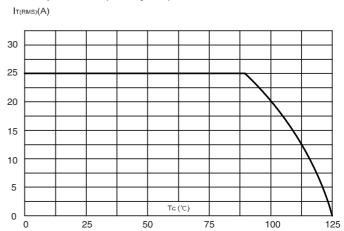


FIG.4:Surge peak on-state current versus number of cycles.

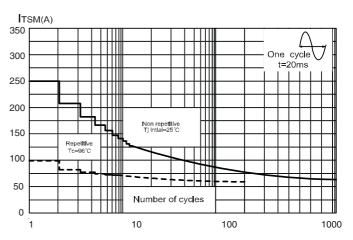
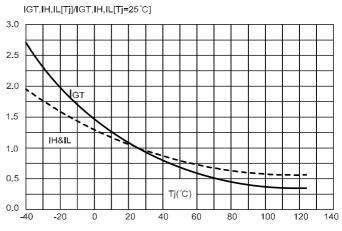


FIG.6:Relative variations of gate trigger current, holding current and latching current versus junction temperature(typical values)





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